



## Selection Guide

Part No.	Dice	Lens Type	Iv (ucd) @ 10 mA		Description
			Min.	Typ.	
APBA02-41EWA	HIGH EFFICIENCY RED(GaAsP/GaP)	WHITE DIFFUSED	1200	5800	Common Anode. Rt.Hand Decimal

## Electrical / Optical Characteristics at T<sub>A</sub>=25°C

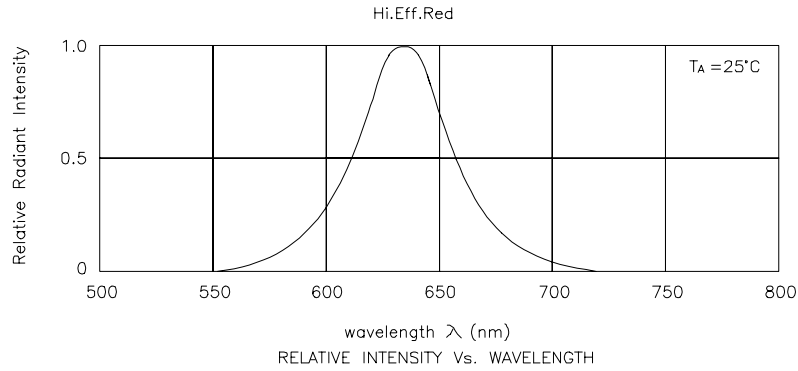
Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
$\lambda_{peak}$	Peak Wavelength	High Efficiency Red	627		nm	I <sub>F</sub> =20mA
$\lambda_D$	Dominate Wavelength	High Efficiency Red	625		nm	I <sub>F</sub> =20mA
$\Delta\lambda_{1/2}$	Spectral Line Half-width	High Efficiency Red	45		nm	I <sub>F</sub> =20mA
C	Capacitance	High Efficiency Red	15		pF	V <sub>F</sub> =0V;f=1MHz
V <sub>F</sub>	Forward Voltage	High Efficiency Red	2.0	2.5	V	I <sub>F</sub> =20mA
I <sub>R</sub>	Reverse Current	High Efficiency Red		10	uA	V <sub>R</sub> = 5V

## Absolute Maximum Ratings at T<sub>A</sub>=25°C

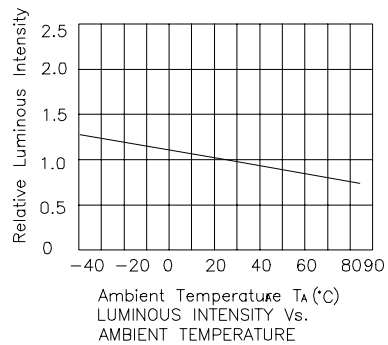
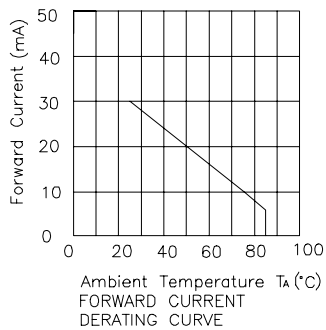
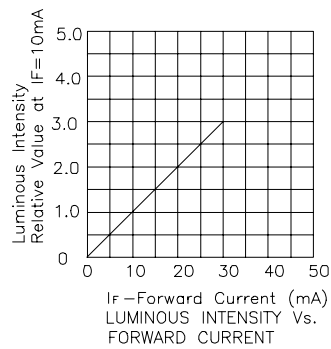
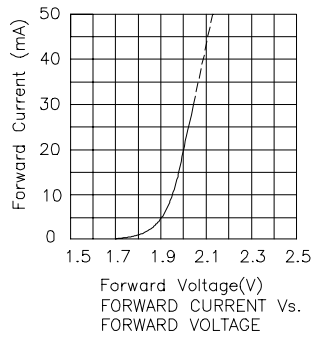
Parameter	High Efficiency Red	Units
Power dissipation	105	mW
DC Forward Current	30	mA
Peak Forward Current [1]	160	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	

Note:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

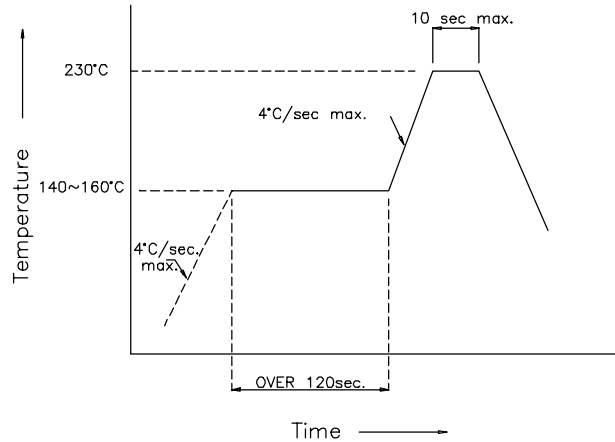


## High Efficiency Red APBA02-41EWA

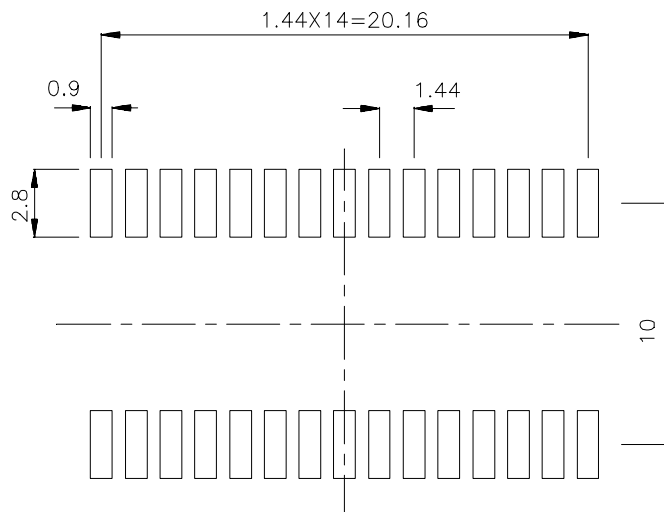


## APBA02-41EWA SMT Reflow Soldering Instruction

Number of reflow process shall be less than 2 times and cooling process to normal temperature is required between first and second soldering process.



## Recommended Soldering Pattern (Units : mm)



## Tape Specification (Units : mm)

